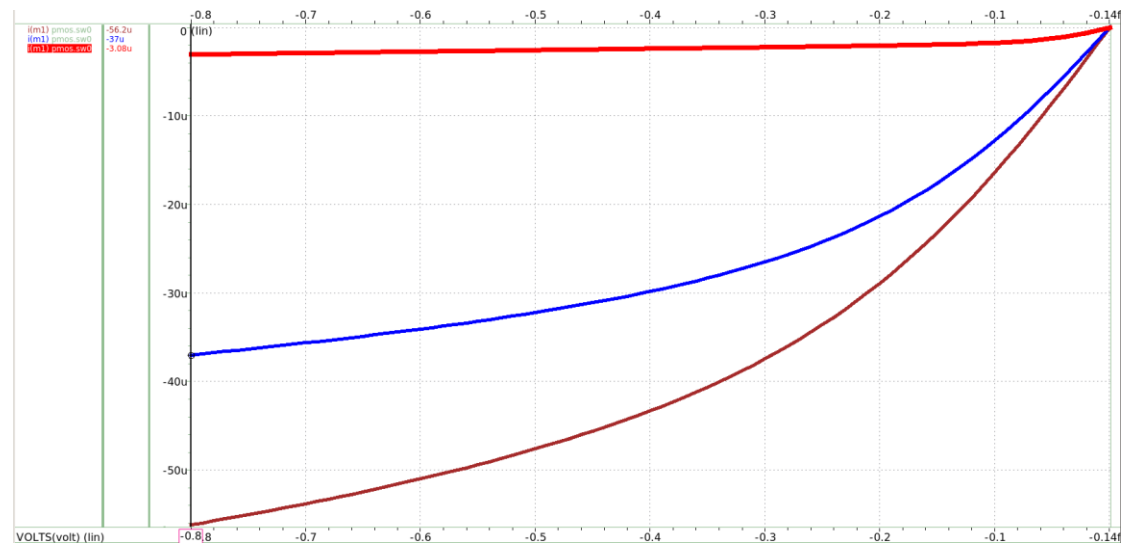


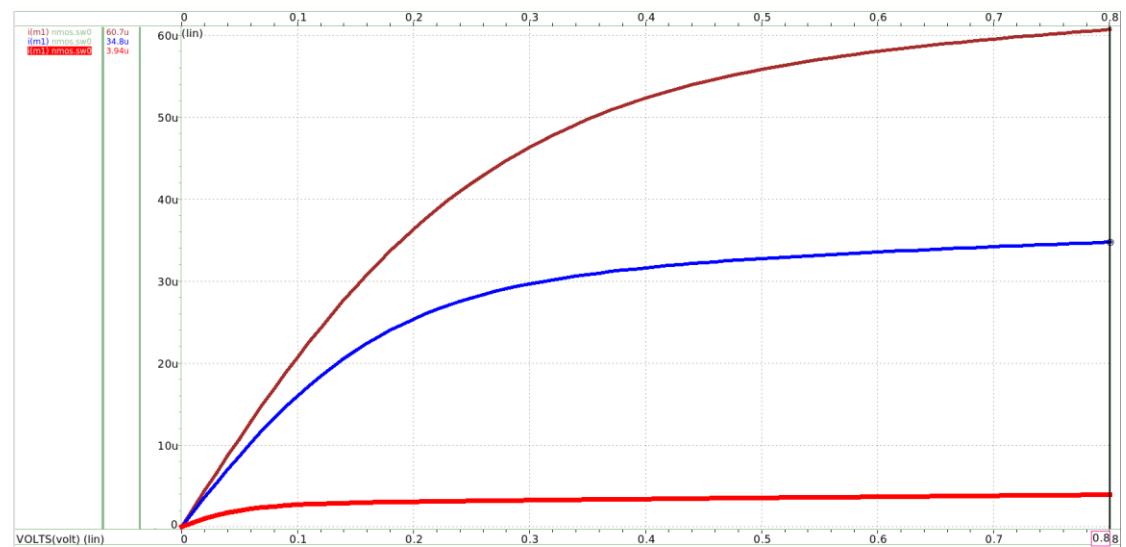
(1) MOS and Inverter (30%)

A. Run SPICE to draw I-V DC curve (like the figure below with $V_{gs} = 0.8, 0.6, 0.35$) for PMOS and NMOS with $F_{in} n=1$. Mark maximum I ($V_{gs}=V_{ds}=VDD$) in table form. Discuss the results.

(a) PMOS I-V curve:



(b) NMOS I-V curve:



(c) Maximum I_{ds} in table form:

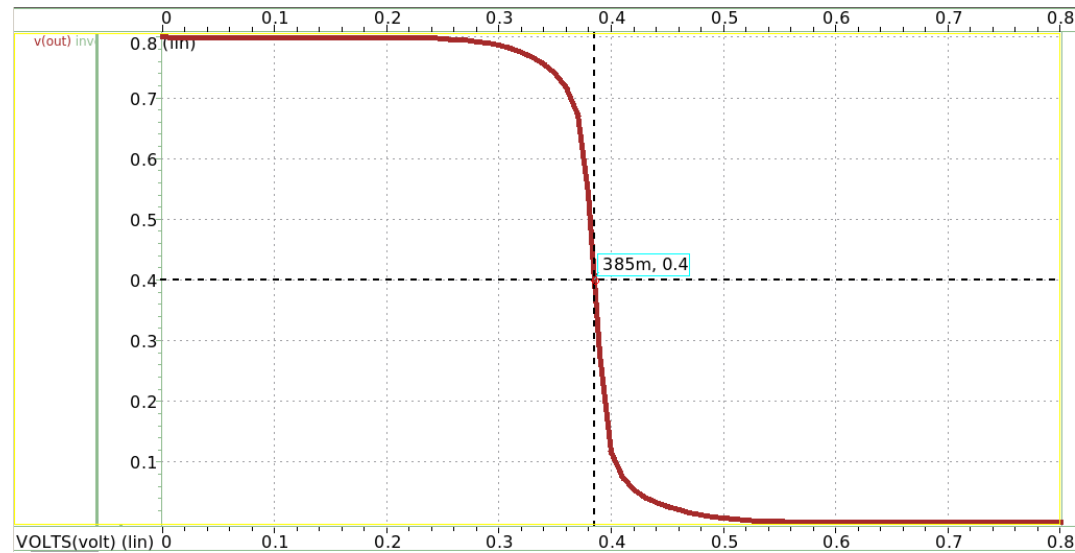
	I_{ds}		
	$ V_{gs} = 0.8v$	$ V_{gs} = 0.6v$	$ V_{gs} = 0.35v$
PMOS	-56.2uA	-37uA	-3.08uA
NMOS	60.7uA	34.8uA	3.94uA

(d) Discuss the result:

由上表可以發現 7nm FinFET 製程的 NMOS 與 PMOS 的電流大小非常接近，不像在 32nm 製程中 NMOS 的電流會是 PMOS 的兩倍之多。我們以往會習慣將 PMOS 大小調成 NMOS 的兩倍左右以平衡電流大小，得到一個 rise 和 fall 速度一致的元件，但在 7nm FinFET 製程中我們只需要把大小設的差不多。

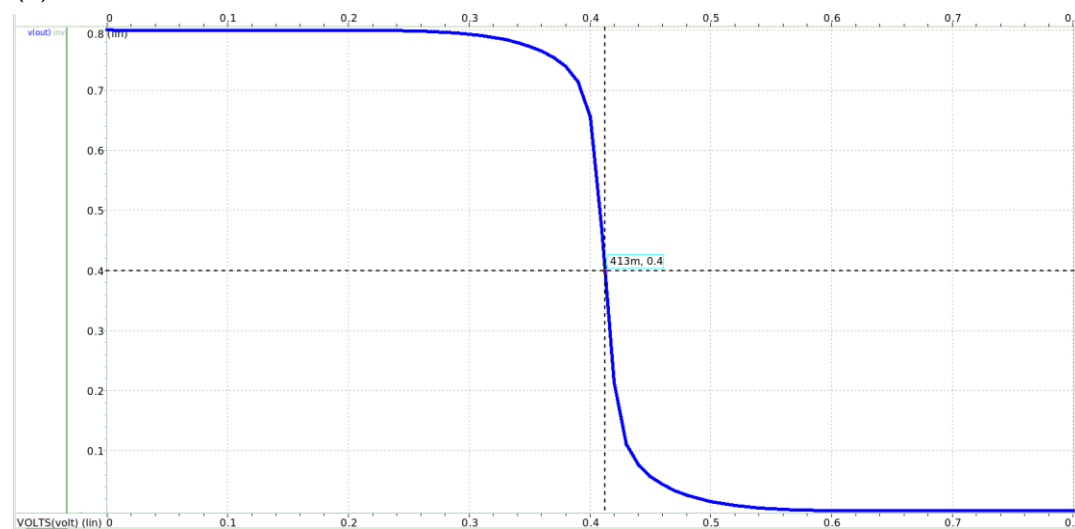
B. Keep a unit size inverter with NMOS $n=1$ and choose the n of PMOS for $n=1$ and 2 to show the logic threshold voltage. Run SPICE to verify your results by showing simulated waveforms.

(a) The waveform of $n = 1$:



According to the figure above, when input = 0.385V, the output = $0.5V_{DD} = 0.4V$.

(b) The waveform of $n = 2$:



According to the figure above, when input = 0.413V, the output = $0.5V_{DD} = 0.4V$.

(c) Discuss the result:

The following table shows the logic threshold voltage for $n = 1$ and $n = 2$.

	$n = 1$	$n = 2$
Logic threshold voltage	0.385V	0.413V

According to the table, 0.413V is closer to 0.4V. Therefore, I choose $n = 2$ as my unit size inverter.

(2) Ring Oscillator (20%)

According to the results of (1)B, design a 3-stage inverter-based ring oscillator with unit size inverter. Set the initial voltage of each node so that it can oscillate. Show the SPICE simulation results of oscillation frequency and power consumption in table form.

Here's my code of oscillator:

```
*****
** . . . . .Circuit description . . . . .
*****

.subckt inverter A Y
MP Y A vdd! vdd! pmos_rvt nfin = 2
MN Y A gnd! gnd! nmos_rvt nfin = 1
.ends

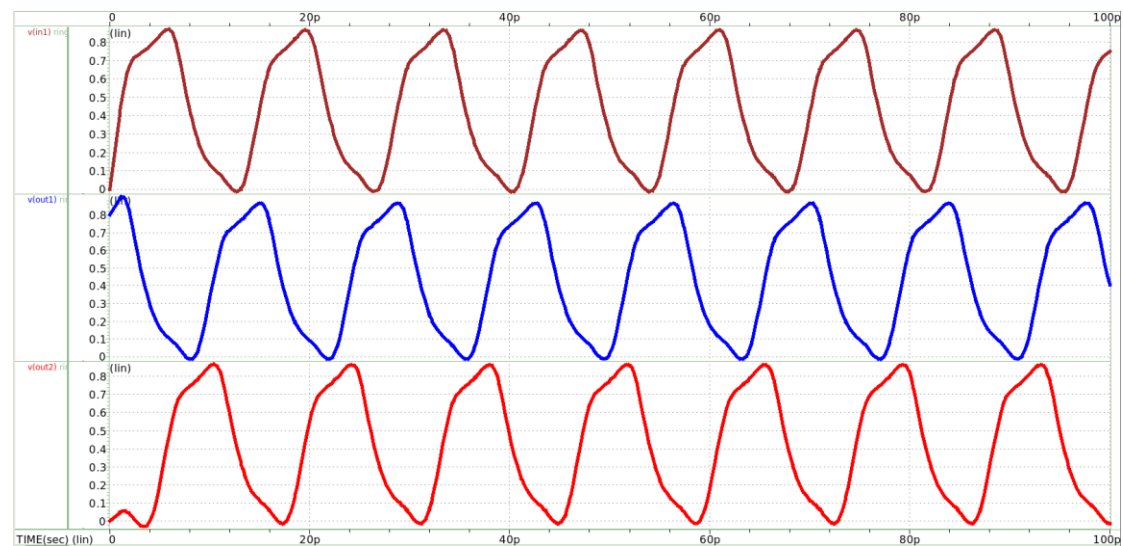
xinv1 in1 out1 inverter
xinv2 out1 out2 inverter
xinv3 out2 in1 inverter
```

接著利用 `.ic v(in1) = 0` (如下圖)，將 `in1` 的電壓初始化為 0，這樣輸入訊號就會通過 3 級 inverter 開始震盪。我個人是模擬 100 ps:

```
*****
** . . . . .Analysis setting . . . . .
*****

.ic v(in1) = 0
.tran 1ps 100ps
```

The waveform of the three nodes, respectively:



(a) Show the SPICE simulation results of oscillation frequency:

Here's my code measuring the period of clock:

```
.meas tran period trig V(out1) val = 0.4 rise = 2 targ V(out1) val = 0.4 rise = 3
```

Here's the simulation result:

```
period= 13.7750p targ= 37.8365p trig= 24.0615p
```

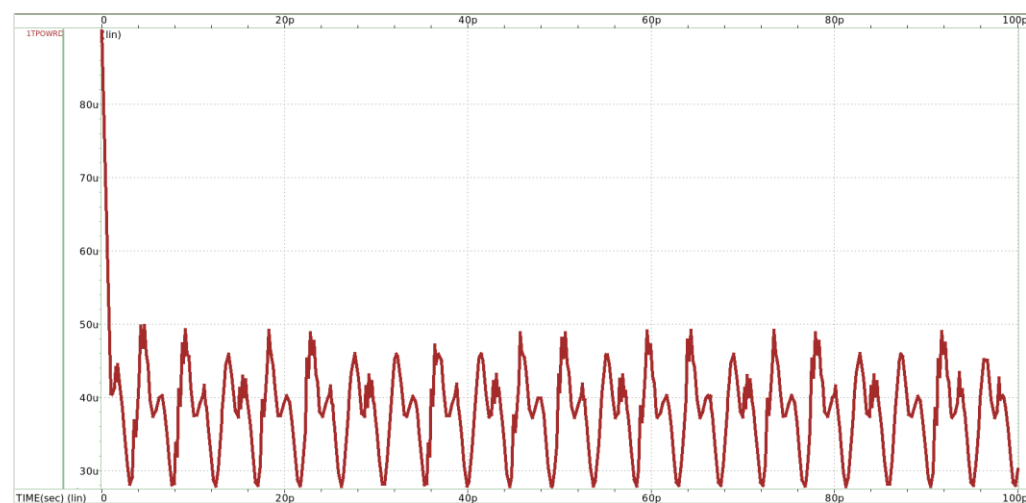
Therefore, the frequency is $\frac{1}{13.7750 \times 10^{-12}} = 72.5953 \text{ GHz}$.

(b) Show the SPICE simulation results of power consumption

下圖是我量 power 的 code，我量了 average power 以及 peak power。此外，我看 power 的波型圖在最一開始衝得很高，我覺得那算離群值，所以我從 10ps 才開始取 data。

```
.tran 1ps 100ps  
.probe power = par(' -p(vvdd) ' )  
.meas tran avgpwr AVG power from = 10p to = 90p  
.meas tran peakpwr MAX power from = 10p to = 90p
```

Here's the power waveform:



Here's the simulation result of power:

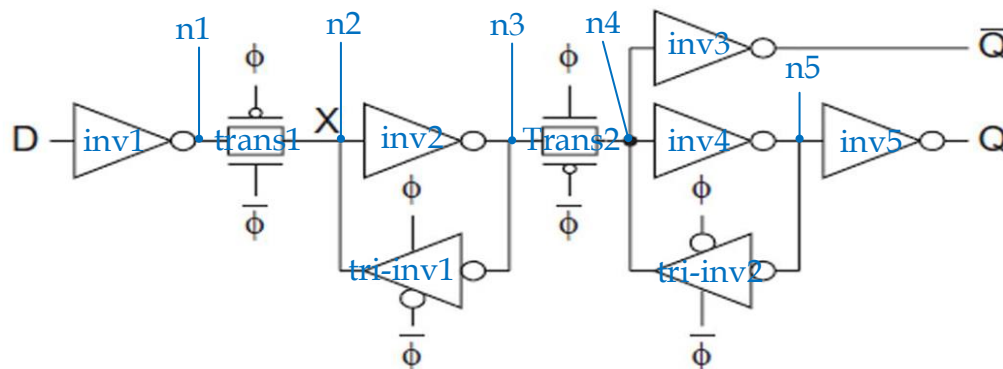
```
avgpwr= 37.9873u from= 10.0000p to= 90.0000p  
peakpwr= 49.1717u at= 73.3988p  
from= 10.0000p to= 90.0000p
```

In conclusion, average power = 37.9873 uW and peak power = 49.1717 uW.

(c) Table form:

Oscillation period	13.7750 ps
Oscillation frequency	72.5953 GHz
Average power	37.9873 uW
Peak power	49.1717 uW

A. Explain your sizing principle of each MOS to have least t_{setup} , t_{pcq} , t_{pdq} , and t_{hold} for logic 1 and 0. (Explain that by changing which transistors would affect each timing respectively)



Setup time 取決於前半部的 DFF，也就是 D-> inv1 -> trans1 -> inv2-> tri-
inv1，改變 n2 及 n3 並穩定所需的時間。因此:

- (b) t_{hold} :

(c) t_{pcq} :

clk 從 0 變 1，n3 經過 trans2 -> inv3 -> tri-inv2 -> inv3 -> inv4，得到穩定輸出 Q 所需的時間。因此:

- inv5 需要強一點，否則會推不動 Q 後面接的 loading。
- inv4 需要次強，用來推動 inv5 以及 tri-inv2。
- tri-inv2 弱一點，因為 tri-inv2 只是用來維持 trans2 的 output 而已。

無論是 logic 0 或 1，各個 MOS 的 size 對 timing 的影響都符合上述趨勢。除非有特定需求，比方說要把 Q 的 0 拉到 1，則會需要特別調大 PMOS。

(d) My MOS size:

Here's the table showing the size for each MOS.

	PMOS	NMOS
inv1	5	5
trans1	1	1
inv2	2	2

	PMOS1	PMOS2	NMOS1	NMOS2
tri-inv1	1	1	1	1

	PMOS	NMOS
trans2	1	1
inv3	3	3
inv4	2	2
inv5	3	3

	PMOS1	PMOS2	NMOS1	NMOS2
tri-inv2	1	1	1	1

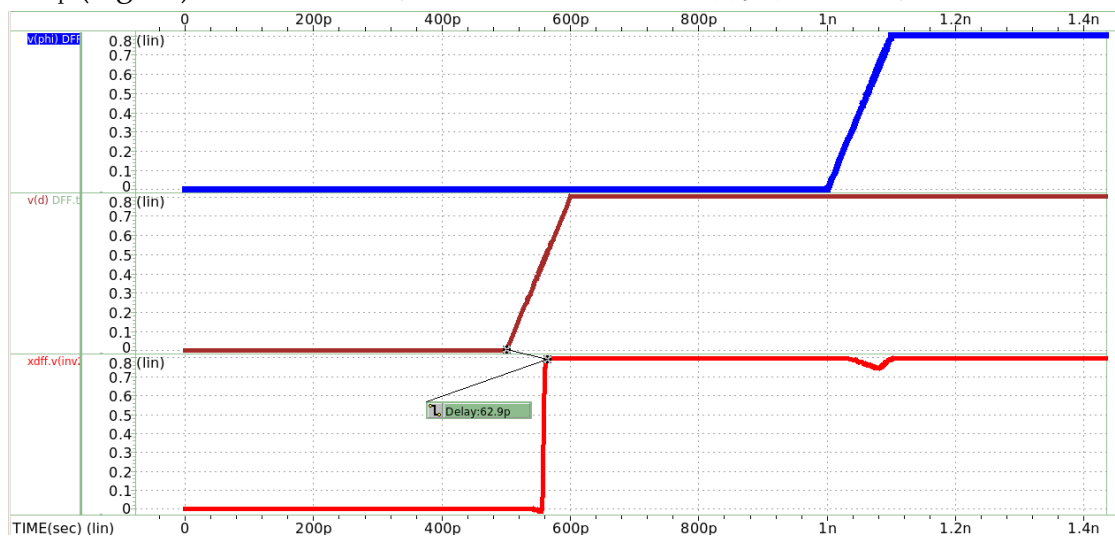
B. Run SPICE to verify your results and list the results (size of each transistor and four kinds of timing) in table form for part A.

(a) t_{setup} (logic 0): 當 D 的值改成 0 時，看 n3 的值會多快跟著改成 0。



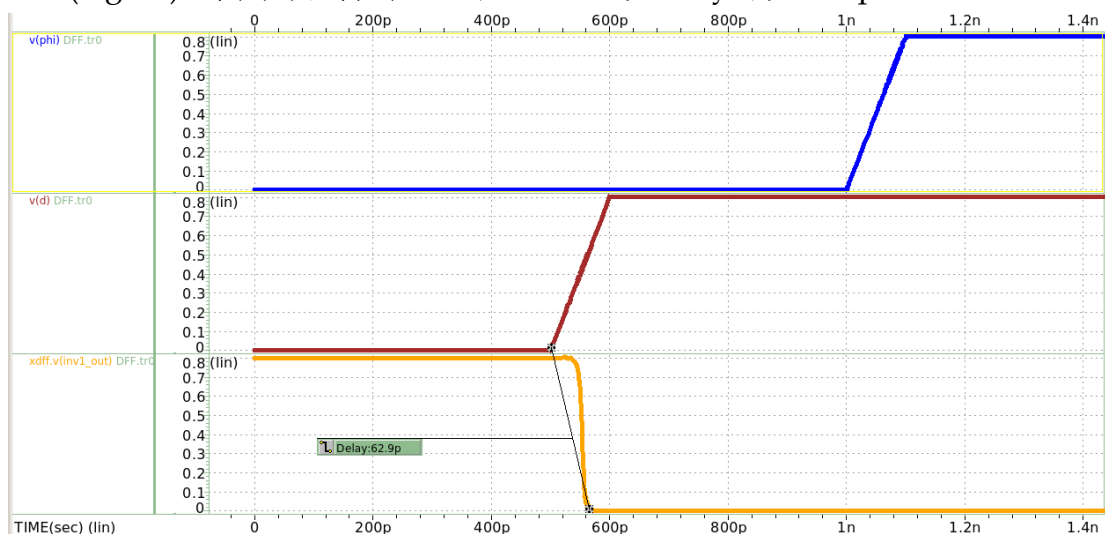
$t_{\text{setup}}=67.6\text{ps}$

(b) t_{setup} (logic 1): 當 D 的值改成 1 時，看 n3 的值會多快跟著改成 1。



$t_{\text{setup}}=62.9\text{ps}$

(c) t_{hold} (logic 0): 下圖可以看出 D 經過 inv1 的 delay 有 62.9 ps。



我在製程檔中看 nmos 的 $V_t = 0.48$ 及 pmos 的 $V_t = 0.4$ ，也就是說當 $\phi = 0.48\text{V}$ 時 tran1 會關閉。又因為 rising time 是 0.1ns ，所以 $0.048\text{ns} = 48\text{ps}$ 時 tran1 會關閉。D 經過 inv1 的 delay 要 62.9ps ，但 tran1 關閉只需 48ps 。因此 D 其實在 posedge clk 後怎麼改值都沒關係，因為經過 62.9ps 的 delay 後 tran1 也早已關閉，因此 $t_{\text{hold}} = 0\text{ps}$ 。

(d) t_{hold} (logic 1): 下圖可以看出 D 經過 inv1 的 delay 有 62.9 ps。



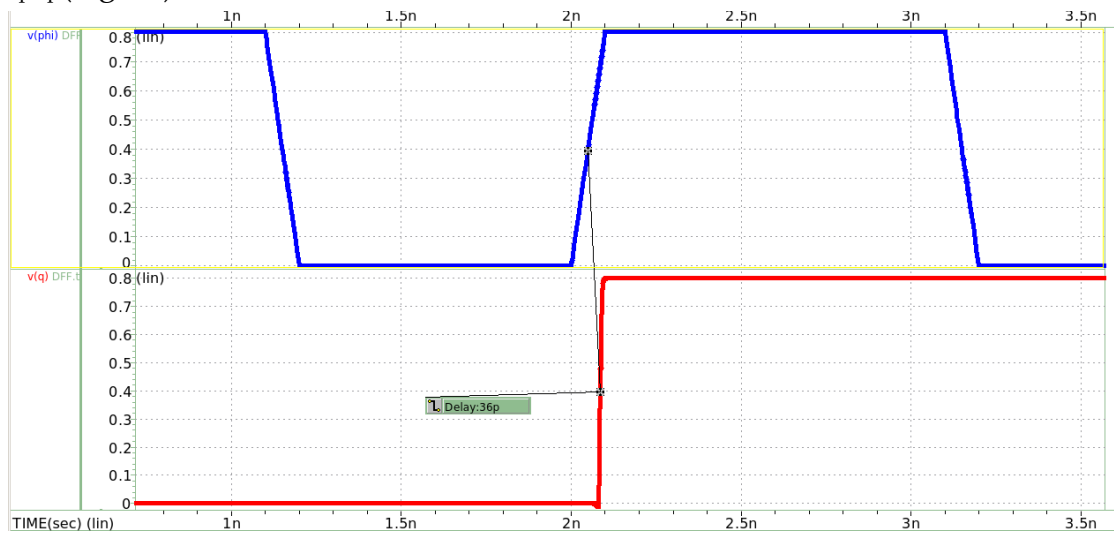
同理(c)，因此 $t_{\text{hold}} = 0\text{ps}$ 。

(e) t_{pcq} (logic 0):



$t_{pcq} = 31.9 \text{ ps}$

(f) t_{pcq} (logic 1):



$t_{pcq} = 36 \text{ ps}$

(g) list the results in table form:

Here's the table showing the size for each MOS.

	PMOS	NMOS
inv1	5	5
trans1	1	1
inv2	2	2

	PMOS1	PMOS2	NMOS1	NMOS2
tri-inv1	1	1	1	1

	PMOS	NMOS
trans2	1	1

inv3	3	3
inv4	2	2
inv5	3	3

	PMOS1	PMOS2	NMOS1	NMOS2
tri-inv2	1	1	1	1

Here's the table of timing.

	t_{setup}	t_{hold}	t_{pcq}
Logic 0	67.6ps	0ps	31.9ps
Logic 1	62.9ps	0ps	36ps